

DATA SHEET

AS222-92, AS222-92LF: PHEMT GaAs IC SPDT Switch 0.1–3 GHz

Applications

- T/R switch in WLANs, Bluetooth™ and medium-power telecommunication applications


Features

- Low insertion loss
- Isolation 22 dB @ 2.4 GHz
- Low DC power consumption
- Operates with 1.8 V control voltage
- Available lead (Pb)-free and RoHS-compliant MSL-1 @ 260 °C per JEDEC J-STD-020

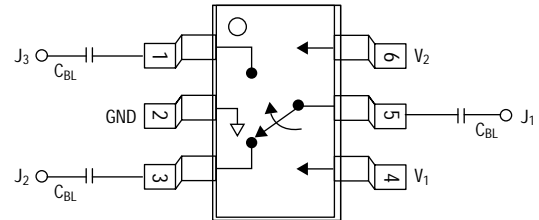
Description

The AS222-92 is a medium-power IC FET SPDT switch in a low-cost miniature SC-70 6-lead plastic package. The AS222-92 features low insertion loss and positive voltage operation with very low DC power consumption. This general-purpose switch can be used in a variety of telecommunications applications.

NEW Skyworks offers lead (Pb)-free, RoHS (Restriction of Hazardous Substances)-compliant packaging.



Pin Out



DC blocking capacitors (C_{BL}) must be supplied externally for positive voltage operation. $C_{BL} = 100$ pF for operation >500 MHz.

Electrical Specifications at 25 °C (0, 3 V)

Parameter ⁽¹⁾	Frequency	Min.	Typ.	Max.	Unit
Insertion loss ⁽²⁾	0.1–1.0 GHz		0.35	0.5	dB
	1.0–2.4 GHz		0.45	0.6	dB
	2.4–3.0 GHz		0.50	0.7	dB
Isolation	0.1–1.0 GHz	24	27		dB
	1.0–2.4 GHz	19	22		dB
	2.4–3.0 GHz	16	18		dB
Return loss ⁽³⁾	0.1–1.0 GHz		19		dB
	1.0–2.4 GHz		21		dB
	2.4–3.0 GHz		18		dB

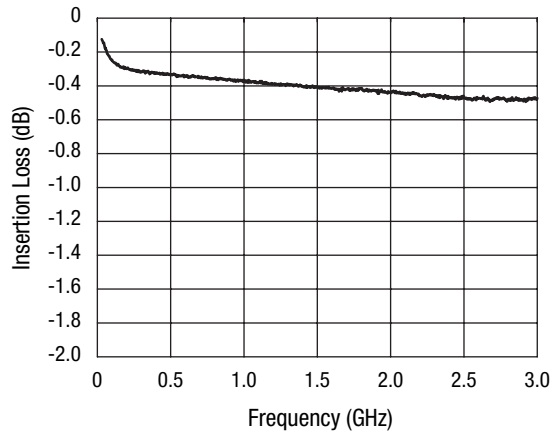
1. All measurements made in a 50 Ω system, unless otherwise specified.
 2. Insertion loss changes by 0.003 dB/°C.
 3. Insertion loss state.

 **Innovation to Go™**
 Now available for purchase online.

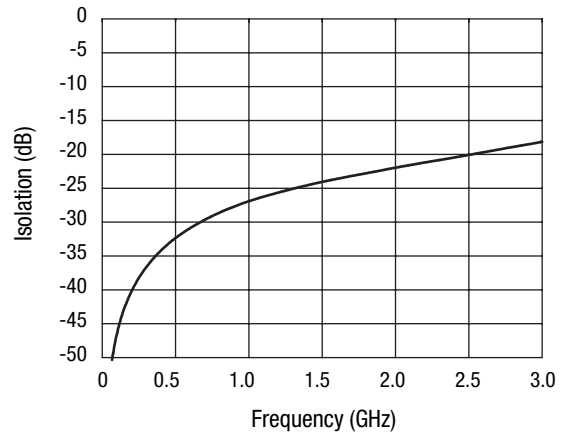
Operating Characteristics at 25 °C (0, 3 V)

Parameter	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching characteristics						
Rise, fall	10/90% or 90/10% RF			20		ns
On, off	50% CTL to 90/10% RF			20		ns
Video feedthru	T _{RISE} = 1 ns, BW = 500 MHz			25		mV
Input power for 1 dB compression	V _{CTL} = 0/1.8 V V _{CTL} = 0/3 V	0.5–3 GHz 0.5–3 GHz		20 27		 dBm
Intermodulation intercept point (IP3)	For two-tone input power 5 dBm V _{CTL} = 0/3 V	0.5–3 GHz		44		dBm
Thermal resistance				25		°C/W
Control voltage	V _{CTL} = High V _{CTL} = Low		1.8 0		5.0 0.2	 V
Control port current	V _{CTL} = 5 V V _{CTL} = 2.5 V V _{CTL} = 0.2 V V _{CTL} = 0 V				200 100 20 20	 μA μA μA μA

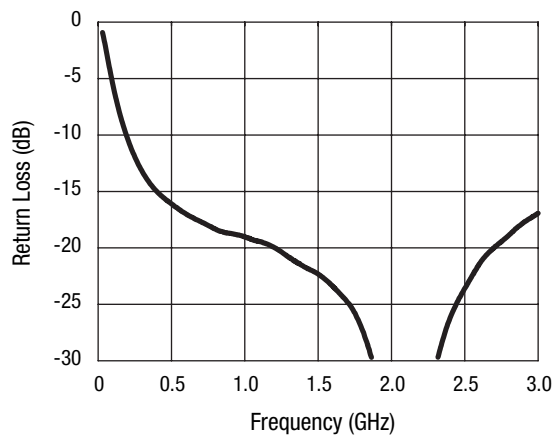
Typical Performance Data (0, 3 V)



Insertion Loss vs. Frequency



Isolation vs. Frequency



Return Loss vs. Frequency

Absolute Maximum Ratings

Characteristic	Value
RF input power	2 W max. > 500 MHz 0/8 V control
Supply voltage	8 V
Control voltage	-0.2 V, +8 V
Operating temperature	-40 °C to +85 °C
Storage temperature	-65 °C to +150 °C

Performance is guaranteed only under the conditions listed in the specifications table and is not guaranteed under the full range(s) described by the Absolute Maximum specifications. Exceeding any of the absolute maximum/minimum specifications may result in permanent damage to the device and will void the warranty.

CAUTION: Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions must be employed at all times.

Truth Table

V ₁	V ₂	J ₁ -J ₂	J ₁ -J ₃
V _{HIGH}	0	Isolation	Insertion loss
0	V _{HIGH}	Insertion loss	Isolation

All other conditions not recommended.
V_{HIGH} = 1.8 to 5 V.

SC-70 6-Lead

